

Docket No.: 60188-431



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**PATENT** RECEIVED  
SEP 23 2003  
TECHNOLOGY CENTER 2600

In re Application of : Customer Number: 20277  
Akihiko ISHIBASHI, et al. : Confirmation Number: 6491  
Serial No.: 10/017,389 : Group Art Unit: 2818  
Filed: December 18, 2001 : Examiner: Mai Huong C. Tran  
For: METHOD FOR FABRICATING SEMICONDUCTOR, METHOD FOR FABRICATING  
SEMICONDUCTOR SUBSTRATE, AND SEMICONDUCTOR LIGHT EMITTING  
DEVICE

**SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT**

Mail Stop DD  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the reference listed on the attached form PTO-1449. It is respectfully requested that the reference be expressly considered during the prosecution of this application, and that the reference be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

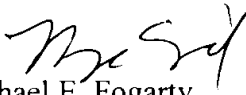
This Information Disclosure Statement ("IDS") is supplemental to the IDS filed on August 14, 2003, and includes a partial English translation of JP 10-150245 cited therein.

10/017,389

Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

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**Date: September 17, 2003**

